

Ideal shear strain of metals and ceramics

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Using density functional theory we analyze the stress-strain responses of 22 simple metals and ceramics to determine the maximum shear strain a homogeneous crystal can withstand, a property for which we suggest the name shearability. A shearability gap is found between metals and covalent ceramics. Shearability of metals further correlates with the degree of valence charge localization and directional bonding. Depending on the deformation constraints, ionic solids may possess even larger shearability than covalent solids. The Frenkel model of ideal shear strength works well for both metals and ceramics when shearability is used in the scaling.

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The ductility of solids is controlled by the energy needed to break a bond by shear compared to that by tension.¹⁻⁷ It is characteristic of ceramics to have a larger ratio of shear to bulk moduli; however, little is known about the range of shear deformation in solids with different types of bonding. The maximum shear and tensile distortions that chemical bonding can withstand are particularly important for defects, e.g., dislocation cores and crack tips.^{6,7} A first step toward better understanding begins with two aspects of affine deformation of perfect crystals. One is the elastic constant describing the linear response of the lattice to small strain, and the other is a fundamental characterization of the large-strain nonlinear response.⁸⁻¹¹ While use of the former in scaling relations is almost universal in defect mechanics, the question of whether the latter also factors into microstructure-controlling quantities such as the intrinsic stacking fault energy has been examined only recently.¹² Here we apply density functional theory (DFT) to compute the shearability and tensibility of simple metals and ceramics, defined by the maximum shear and tensile strains at which a perfect crystal under affine deformation becomes unstable, to bring out the fundamental connection between critical mechanical response of a solid and the underlying electronic structure such as redistribution of valence charge density. To be precise, we define shearability as $s_m \equiv \arg \max \sigma(s)$, where $\sigma(s)$ is the resolved shear stress and s is the engineering shear strain in a specified slip system. Similarly, tensibility is taken to be $t_m \equiv \arg \max -P((1+t)V_0)$, where $P(V)$ is the pressure-volume relation and V_0 is the equilibrium volume, $P(V_0) = 0$.

We have studied the following metals and ceramics using the Vienna *Ab-Initio* Simulation Package¹³: FCC Ag, Cu, Au, ferromagnetic (FM) and paramagnetic (NM) Ni, Al; BCC W, Mo, Fe (FM); HCP Mg, Ti, Zn; L1₀ TiAl, D0₁₉ Ti₃Al; diamond cubic C, Si; β -SiC, α -, β -Si₃N₄; B1 NaCl, MgO, KBr, CaO. The exchange-correlation density functionals adopted are Perdew-Wang generalized gradient

approximation (GGA) for metals except Au and Ag, and Ceperley-Alder local density approximation (LDA) for the others. Ultrasoft (US) pseudopotential is used in most cases, but for difficult systems we switch to the projector augmented-wave (PAW) method.¹⁴ Brillouin zone (BZ) k -point sampling is performed using the Monkhorst-Pack algorithm. For metals, BZ integration follows the Methfessel-Paxton scheme¹⁵ with the smearing width chosen so the “-TS” term is less than 0.5 meV/atom. For nonmetallic systems, the tetrahedron method with Blöchl corrections¹⁶ is used.

Incremental affine shear strains are imposed on each crystal along experimentally determined common slip systems to obtain the corresponding unrelaxed and relaxed energies and stresses, defined respectively by the conditions, $\epsilon_{ij} = 0$ except $s \equiv x/d_0$ with d_0 being the interplanar separation and x taken along the Burgers vector, and $\sigma_{ij} = 0$ except for the resolved shear stress. For α -, β -Si₃N₄, the common slip systems are unknown experimentally. We therefore calculate six systems for each phase, and take the one that has the lowest ideal shear strength.¹⁷

In Table I, the equilibrium lattice constants $a_0(c_0)$ obtained from energy minimization, with attention to energy cutoff E_{cut} and k -sampling convergence, are compared with experimental results. In Table II, the calculated relaxed and unrelaxed shear moduli G_r, G_u in the specified slip systems are compared with analytical values computed from experimental elastic constants. The resolved moduli are calculated using fine meshes $\Delta s = 0.5\% - 1\%$ along the shear path, whereas coarser meshes $\Delta s = 1\% - 5\%$ are used to interpolate the $\sigma(s)$ curves. Affine stress components are relaxed to within a convergence tolerance 0.05 GPa, and in crystals with internal degrees of freedom, the force on each atom is relaxed to less than 0.01 eV/Å.

The relaxed ideal shear stress σ_m^r normalized by G_r and the shearability s_m^r for different materials are plotted together in Fig. 1(a). For simplicity we display only results in the experimentally determined primary slip system, except for

TABLE I. Equilibrium properties: Calculation vs experiment.

| Material | # atoms | Method | # k -points | $E_{\text{cut}}[\text{eV}]$ | $a_0, c_0[\text{\AA}]$ | | Expt. Elastic const [GPa] | | | | |
|--|---------|---------|--------------------------|-----------------------------|------------------------|----------------------------|---------------------------|----------|----------|----------|--------------------|
| | | | | | Calc. | Expt. | C_{13} | C_{33} | C_{11} | C_{12} | C_{44} |
| C | 2 | US-LDA | $6 \times 6 \times 6$ | 358.2 | 3.53 | 3.567 ^d | | | 1079.3 | 125 | 578.9 ^e |
| Si | 2 | US-LDA | $5 \times 5 \times 5$ | 188.2 | 5.39 | 5.4238 ^e | | | 167 | 65 | 80 ^e |
| β -SiC | 2 | US-LDA | $6 \times 6 \times 6$ | 358.2 | 4.32 | 4.36 ^e | | | 390 | 142 | 256 ^k |
| α -Si ₃ N ₄ | 28 | US-LDA | $4 \times 4 \times 4$ | 434.8 | 7.70,5.58 | 7.818,5.591 ^f | | | | | |
| β -Si ₃ N ₄ | 14 | US-LDA | $4 \times 4 \times 8$ | 434.8 | 7.56,2.88 | 7.595,2.9023 ^g | 127 | 574 | 433 | 195 | 108 ^l |
| NaCl | 8 | US-LDA | $6 \times 6 \times 6$ | 274.1 | 5.46 | 5.593 ^e | | | 57 | 11.5 | 13.3 ^e |
| KBr | 8 | US-LDA | $6 \times 6 \times 6$ | 207.1 | 6.36 | 6.566 ^e | | | 43 | 4.8 | 5.4 ^e |
| MgO | 8 | US-LDA | $6 \times 6 \times 6$ | 494.6 | 4.14 | 4.2072 ^e | | | 306 | 93 | 158 ^e |
| CaO | 8 | US-LDA | $6 \times 6 \times 6$ | 494.6 | 4.57 | 4.80 ^e | | | 210 | 67 | 74 ^e |
| Mo | 1 | US-GGA | $31 \times 31 \times 31$ | 233.1 | 3.15 | 3.144 ^e | | | 476 | 158 | 111 ^e |
| W | 1 | US-GGA | $31 \times 31 \times 31$ | 235.2 | 3.17 | 3.0213 ^e | | | 534 | 205 | 163 ^e |
| Fe ^a | 1 | PAW-GGA | $31 \times 31 \times 31$ | 334.9 | 2.83 | 2.8603 ^h | | | 243 | 138 | 122 ^e |
| Ti ^c | 2 | PAW-GGA | $27 \times 27 \times 17$ | 278.0 | 2.93,4.63 | 2.9457,4.6727 ^e | 68.3 | 190.5 | 176 | 86.9 | 50.8 ^m |
| Mg | 2 | PAW-GGA | $39 \times 39 \times 25$ | 262.6 | 3.19,5.18 | 3.2094,5.2103 ^e | 21.7 | 66.5 | 63.5 | 25.9 | 18.4 ^e |
| Zn | 2 | PAW-GGA | $33 \times 33 \times 23$ | 345.9 | 2.64,5.04 | 2.6638,4.9431 ^e | 52 | 69 | 178 | 35 | 46 ^e |
| TiAl | 4 | US-GGA | $21 \times 21 \times 21$ | 226.5 | 3.98,4.08 | 3.975,4.068 ⁱ | 74.8 | 182 | 187 | 74.8 | 109 ^j |
| Ti ₃ Al | 8 | US-GGA | $15 \times 15 \times 17$ | 226.5 | 5.74,4.65 | 5.814,4.649 ^j | 62.6 | 225.1 | 183.2 | 89.0 | 64.1 ^j |
| Al | 6 | US-GGA | $18 \times 25 \times 11$ | 161.5 | 4.04 | 4.0321 ^e | | | 114 | 62 | 30.8 ^e |
| Ni ^a | 1 | US-GGA | $31 \times 31 \times 31$ | 302 | 3.53 | 3.5136 ^e | | | 262 | 151 | 132 ^e |
| Ni ^b | 1 | US-GGA | $31 \times 31 \times 31$ | 302 | 3.52 | | | | | | |
| Ag | 1 | US-LDA | $31 \times 31 \times 31$ | 225.8 | 4.02 | 4.07 ^e | | | 132 | 97 | 51 ^e |
| Au | 1 | US-LDA | $43 \times 43 \times 43$ | 224.6 | 4.06 | 4.08 ^e | | | 202 | 169 | 45.3 ^e |
| Cu | 6 | US-GGA | $12 \times 17 \times 7$ | 292.2 | 3.64 | 3.616 ^e | | | 176.2 | 124.9 | 81.8 ^e |

^aFerromagnetic.^bParamagnetic.^c p -valence.^dReference 23.^eReference 24.^fReference 27.^gReference 28.^hReference 30.ⁱReference 31.^jReference 32.^kReference 25.^lReference 29.^mReference 26.

BCC metals where all three slip systems are equally likely,^{8,18} in which case we use the one that gives the minimum σ_m^r . For Ni we plot only the FM case. The corresponding unrelaxed results are shown in Fig. 1(b). Note that relaxation has a particularly pronounced effect in ionic ceramics.

From these results we see gaps in the distributions of s_m^r and s_m^u between the metals and the covalent solids. Such gaps also may be seen by comparing results of previous works for elastic shear instability of metals^{8,12,18} and covalent solids.^{17,19} Moreover, among the metals the noble metals Au, Ag, Cu and the more directionally bonded Al and BCC Mo, W, Fe (FM) are at opposite sides of the distributions. This suggests that directional bonding allows for longer-range shear distortion of the bonds before peak resistance is attained, which one can rationalize by observing that the greater the covalency, the more valence charge will concentrate in non-nuclear-centered regions,^{20,21} e.g., bond centers and other high-symmetry interstices, as can be verified by an examination of the charge density isosurface plots (see Fig. 2, and also Supplementary Material²²). These localized

charge pockets would require certain spatial arrangement among them for the total energy to be well-minimized. In contrast, if the valence charge density in the interstices is completely delocalized, then there would be no such constraints and the energy barrier to shear would come mainly from a misfit-volume effect. In FCC Cu and Ag one can see that when the local interstice volumes completely recover their equilibrium values at the intrinsic stacking fault, the energy penalties are very low, despite the “wrong” bond angles.¹² Consequently a rather general interpretation of our results is that, so far as the rearrangement of charge density in response to mechanical deformation is concerned, bond-angle dependence brings about geometric constraints on the atomic configurations above and beyond the volumetric constraints. From the standpoint of energy landscape, the stable attractive basin of the ground state is steeper and wider in the shear direction because many low-energy metastable states are eliminated or greatly elevated by the extra constraints in configurational space.

TABLE II. Shear moduli G_r (relaxed), G_u (unrelaxed), ideal shear strains s_m^r (relaxed), s_m^u (unrelaxed) and stresses σ_m^r (relaxed), σ_m^u (unrelaxed) in common slip systems.

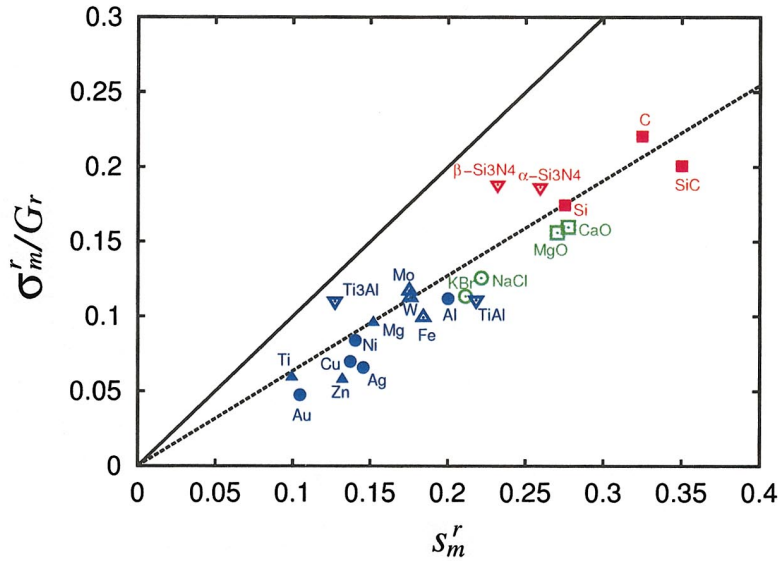
| Material | Slip system | Expt. [GPa] ^a | | G/B [GPa] ^a | | Calc. G_r | [GPa] | | Relaxed | | | Unrelaxed ^b | |
|--|----------------------------------|--------------------------|-------|--------------------------|---------|-------------|-------|-------|---------|--------------------|------------------|------------------------|--------------------|
| | | G_r | G_u | G_r/B | G_u/B | | G_r | G_u | s_m^r | σ_m^r [GPa] | σ_m^r/G_r | s_m^u | σ_m^u [GPa] |
| C | {111}<110> | 506.8 | 511.1 | 1.14 | 1.15 | 514.1 | 519.2 | 0.325 | 113.32 | 0.220 | 0.374 | 146.03 | 0.281 |
| Si | {111}<110> | 57.9 | 60.4 | 0.585 | 0.610 | 55.2 | 58.2 | 0.275 | 9.62 | 0.174 | 0.262 | 11.13 | 0.191 |
| β -SiC | {111}<110> | 149.7 | 168.0 | 0.666 | 0.748 | 158.2 | 173.4 | 0.350 | 31.74 | 0.201 | 0.348 | 43.12 | 0.249 |
| α -Si ₃ N ₄ | {11 $\bar{2}$ 0}<0001> | | | | | 127.3 | 128.4 | 0.259 | 23.72 | 0.186 | 0.295 | 26.48 | 0.206 |
| β -Si ₃ N ₄ | {10 $\bar{1}$ 0}<0001> | 108.0 | 108.0 | 0.417 | 0.417 | 101.0 | 102.0 | 0.232 | 19.00 | 0.188 | 0.244 | 21.00 | 0.206 |
| NaCl | {110}<1 $\bar{1}$ 0> | 22.8 | 22.8 | 0.855 | 0.855 | 29.4 | 29.4 | 0.221 | 3.69 | 0.126 | 0.658 | 25.55 | 0.869 |
| KBr | {110}<1 $\bar{1}$ 0> | 19.1 | 19.1 | 1.09 | 1.09 | 23.2 | 23.2 | 0.211 | 2.62 | 0.113 | 0.610 | 15.41 | 0.666 |
| MgO | {110}<1 $\bar{1}$ 0> | 106.5 | 106.5 | 0.649 | 0.649 | 109.5 | 109.5 | 0.270 | 17.09 | 0.156 | 0.629 | 74.34 | 0.679 |
| CaO | {110}<1 $\bar{1}$ 0> | 71.5 | 71.5 | 0.624 | 0.624 | 101.3 | 101.3 | 0.277 | 16.18 | 0.160 | 0.664 | 72.35 | 0.714 |
| Mo | {110}< $\bar{1}$ 11> | 138.7 | 142.8 | 0.525 | 0.541 | 126.5 | 134.5 | 0.190 | 15.18 | 0.120 | 0.192 | 16.52 | 0.123 |
| Mo | {211}< $\bar{1}$ 11> | 138.7 | 142.8 | 0.525 | 0.541 | 126.8 | 134.1 | 0.175 | 14.84 | 0.117 | 0.177 | 15.99 | 0.119 |
| Mo | {321}< $\bar{1}$ 11> | 138.7 | 142.8 | 0.525 | 0.541 | 126.8 | 134.2 | 0.176 | 14.87 | 0.117 | 0.175 | 15.93 | 0.119 |
| W | {110}< $\bar{1}$ 11> | 164.0 | 164.0 | 0.521 | 0.521 | 153.7 | 155.3 | 0.179 | 17.52 | 0.114 | 0.196 | 17.63 | 0.113 |
| W | {211}< $\bar{1}$ 11> | 164.0 | 164.0 | 0.521 | 0.521 | 154.0 | 155.8 | 0.176 | 17.37 | 0.113 | 0.175 | 17.28 | 0.111 |
| W | {321}< $\bar{1}$ 11> | 164.0 | 164.0 | 0.521 | 0.521 | 153.9 | 155.7 | 0.176 | 17.33 | 0.113 | 0.175 | 17.27 | 0.111 |
| Fe ^c | {110}< $\bar{1}$ 11> | 64.8 | 75.7 | 0.375 | 0.438 | 76.6 | 80.6 | 0.178 | 8.14 | 0.106 | 0.234 | 11.43 | 0.142 |
| Fe ^c | {211}< $\bar{1}$ 11> | 64.8 | 75.7 | 0.375 | 0.438 | 75.6 | 79.9 | 0.184 | 7.51 | 0.099 | 0.236 | 9.95 | 0.124 |
| Fe ^c | {321}< $\bar{1}$ 11> | 64.8 | 75.7 | 0.375 | 0.438 | 75.7 | 80.0 | 0.181 | 7.57 | 0.100 | 0.197 | 9.43 | 0.118 |
| Ti ^e | {1 $\bar{1}$ 00}<11 $\bar{2}$ 0> | 44.6 | 44.6 | 0.406 | 0.406 | 47.6 | 47.8 | 0.099 | 2.82 | 0.059 | 0.144 | 4.92 | 0.103 |
| Mg | {0001}<11 $\bar{2}$ 0> | 18.4 | 18.4 | 0.499 | 0.499 | 19.2 | 19.2 | 0.152 | 1.84 | 0.096 | 0.157 | 2.04 | 0.106 |
| Zn | {0001}<11 $\bar{2}$ 0> | 46.0 | 46.0 | 0.708 | 0.708 | 36.6 | 36.6 | 0.132 | 2.12 | 0.058 | 0.136 | 2.33 | 0.064 |
| TiAl | {111}<11 $\bar{2}$ > | 58.5 | 61.6 | 0.524 | 0.552 | 50.0 | 56.4 | 0.218 | 5.54 | 0.111 | 0.217 | 6.25 | 0.111 |
| Ti ₃ Al | {1 $\bar{1}$ 00}<11 $\bar{2}$ 0> | 47.1 | 47.1 | 0.416 | 0.416 | 50.0 | 50.8 | 0.127 | 5.51 | 0.110 | 0.139 | 5.79 | 0.114 |
| Al | {111}<11 $\bar{2}$ > | 27.4 | 27.6 | 0.345 | 0.348 | 25.4 | 25.4 | 0.200 | 2.84 | 0.110 | 0.210 | 3.73 | 0.147 |
| Ni ^c | {111}<11 $\bar{2}$ > | 68.8 | 81.0 | 0.366 | 0.431 | 60.1 | 79.6 | 0.140 | 5.05 | 0.084 | 0.160 | 6.29 | 0.079 |
| Ni ^d | {111}<11 $\bar{2}$ > | | | | | 48.8 | 60.5 | 0.169 | 3.17 | 0.065 | 0.162 | 4.70 | 0.078 |
| Ag | {111}<11 $\bar{2}$ > | 22.4 | 28.7 | 0.206 | 0.264 | 25.0 | 32.3 | 0.145 | 1.65 | 0.066 | 0.156 | 2.57 | 0.079 |
| Au | {111}<11 $\bar{2}$ > | 20.9 | 26.1 | 0.116 | 0.145 | 17.9 | 22.9 | 0.105 | 0.85 | 0.048 | 0.142 | 1.42 | 0.062 |
| Cu | {111}<11 $\bar{2}$ > | 33.3 | 44.4 | 0.235 | 0.313 | 31.0 | 40.9 | 0.137 | 2.16 | 0.070 | 0.157 | 3.45 | 0.084 |

^aComputed analytically from expt. elastic constants of Table I.^bSubsidiary stress components are unrelaxed, but internal degrees of freedom are relaxed.^cFerromagnetic.^dParamagnetic.^e p -valence.

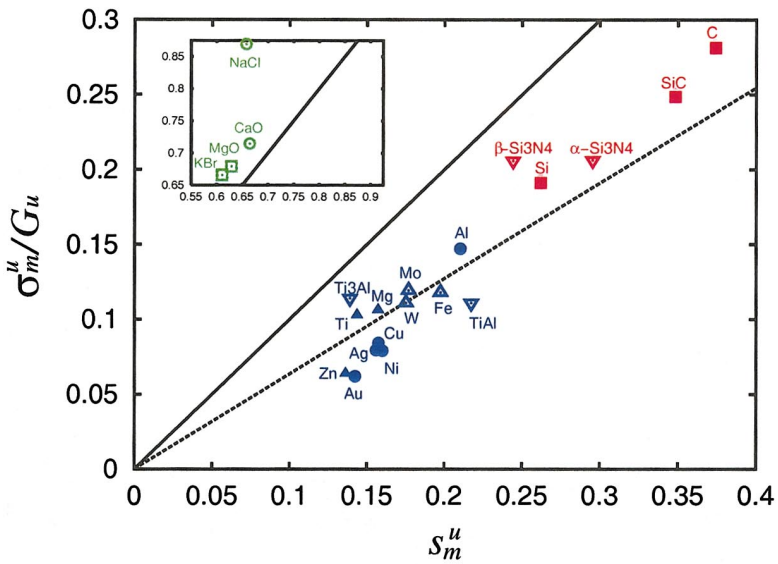
In the relaxed s_m^r , σ_m^r distributions [Fig. 1(a)], ionic ceramics lie midway between directionally-bonded metals and covalent solids, while α - and β -Si₃N₄, being more ionic than SiC, are also in this range.¹⁷ However in unrelaxed shear, these solids manifest abnormally large ideal shear strains s_m^u and stresses σ_m^u , which are attributed to the bare Coulomb repulsion between like-charge ions as in a simple Madelung sum model. In an atomic environment like a crack tip, the surrounding medium would not allow for either fully relaxed or fully unrelaxed local shear. This implies that ionic

materials could be either less or much more brittle than covalent materials, depending on the subsidiary deformation constraints present, a situation that is analogous to the distinction of plane-stress vs plane-strain loading conditions in the fracture of metals.

Another noteworthy feature of Fig. 1 is the approximately universal linear scaling between s_m and σ_m/G across a range of crystal structures, nature of bonding, and slip systems. The original Frenkel mode,¹ containing a single parameter G , is well-known and widely used^{3-5,33} in an empirical fashion. It



(a)



(b)

FIG. 1. (Color) DFT calculation results of 22 materials (metallic: blue, ionic: green, covalent: red). (a) Relaxed, and (b) unrelaxed ideal shear stresses (normalized) and shear strains. The solid line indicates a unit slope, while the dashed line corresponds to a slope of $2/\pi$. The ionic solids are far out of range in (b) and are shown in the inset.

has been pointed out, based on physical intuition, that a more realistic description is to treat the peak position of $\sigma(s)$ as an adjustable parameter^{6,7} rather than as a fixed value at $b/4d_0$. What we have shown here, on the basis of *ab initio* results, is that a two-parameter representation

$$\sigma = \frac{2Gs_m}{\pi} \sin\left(\frac{\pi s}{2s_m}\right), \quad 0 < s < s_m, \quad \sigma_m = \frac{2Gs_m}{\pi} \quad (1)$$

with the shear modulus G and the shearability s_m as fundamental materials parameters, provides a satisfactory description of simple metals and ceramics. As can be seen in Fig. 1 the slope of $2/\pi$, implied by our proposed extension of the

Frenkel model, Eq. (1), indeed represents the data well. Looking at this correlation in another way, we suggest that the fundamental constitutive behavior for shear deformation can be captured in a master curve in terms of normalized stress $\tilde{\sigma} \equiv \sigma/Gs_m$ and strain $\tilde{s} \equiv s/s_m$, as shown in Fig. 3. In this rescaling all curves have initial unit slope and reach maximum at $\tilde{s}=1$. The behavior labeled as Frenkel (renormalized) reflects a universal shear-softening response, for $s < s_m$.

It is worth emphasizing that this new, “renormalized Frenkel” model is the shear counterpart to the Universal Binding Energy Relation² which also has two parameters and has been quantitatively checked against *ab initio* calculations.

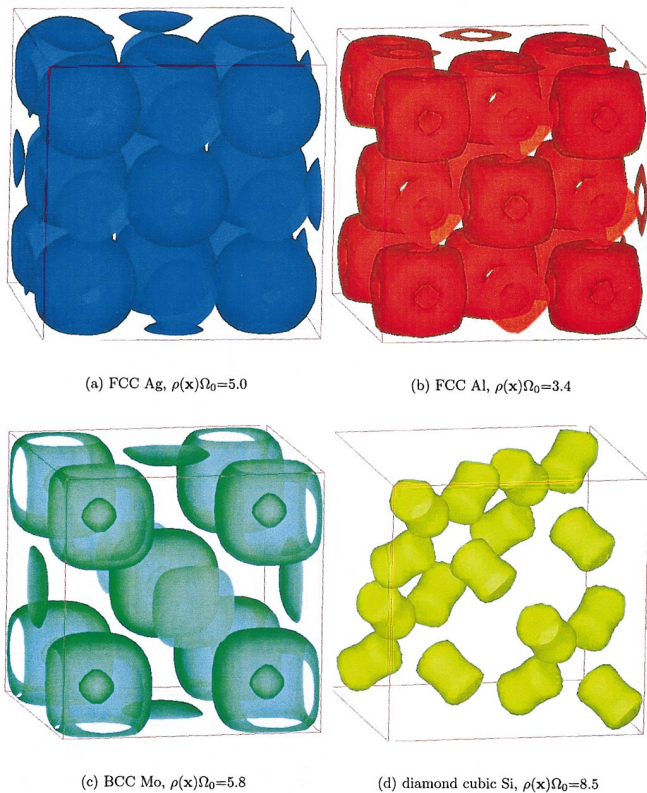


FIG. 2. (Color) Valence charge density $\rho(\mathbf{x})$ isosurface plots of (a) FCC Ag, (b) FCC Al, (c) BCC Mo, (d) diamond cubic Si, at their stress-free states. Ω_0 is the atomic volume.

Taken together they allow materials design and performance criteria to be formulated in which tensile and shear dissipation modes compete.^{5,7,33–35} For example, the “brittleness parameter” of Rice⁵ that compares the unstable stacking energy γ_{us} to the surface energy γ_s , may be very crudely estimated as

TABLE III. Ideal volumetric tensile strain t_m and stress $-P_m$. B is the bulk modulus computed from DFT.

| Material | B [GPa] | t_m | $-P_m$ [GPa] | $-P_m/B$ |
|--|-----------|-------|--------------|----------|
| C | 433.8 | 0.623 | 88.54 | 0.204 |
| Si | 90.16 | 0.510 | 15.43 | 0.171 |
| β -SiC | 213.4 | 0.571 | 40.59 | 0.190 |
| α -Si ₃ N ₄ | 213.9 | 0.488 | 41.49 | 0.194 |
| β -Si ₃ N ₄ | 226.9 | 0.594 | 45.97 | 0.202 |
| NaCl | 28.4 | 0.527 | 5.06 | 0.178 |
| KBr | 18.8 | 0.517 | 3.08 | 0.163 |
| MgO | 152.0 | 0.662 | 31.00 | 0.204 |
| CaO | 104.2 | 0.670 | 22.62 | 0.217 |
| Mo | 243.9 | 0.525 | 43.17 | 0.177 |
| W | 281.3 | 0.535 | 50.17 | 0.178 |
| Fe ^a | 186.5 | 0.576 | 28.45 | 0.153 |
| Ti ^b | 107.7 | 0.618 | 21.48 | 0.200 |
| Mg | 33.3 | 0.515 | 6.01 | 0.180 |
| Zn | 72.5 | 0.384 | 9.54 | 0.132 |
| TiAl | 103.2 | 0.563 | 19.84 | 0.192 |
| Ti ₃ Al | 106.9 | 0.512 | 20.78 | 0.194 |
| Al | 67.5 | 0.507 | 11.15 | 0.165 |
| Ni ^a | 184.0 | 0.500 | 29.24 | 0.159 |
| Ag | 114.3 | 0.514 | 17.62 | 0.154 |
| Au | 167.9 | 0.401 | 23.45 | 0.140 |
| Cu | 130.9 | 0.478 | 20.37 | 0.156 |

^aFerromagnetic.

^b p -valence.

$$\beta \equiv \frac{\gamma_{us}}{\gamma_s} \propto \frac{G s_m^2}{B t_m^2} = \left(\frac{G}{B} \right) \cdot (s_m^2)/(t_m^2) \quad (2)$$

by scaling arguments. G/B (see Table II) is accessible experimentally and has been used as a performance predictor in

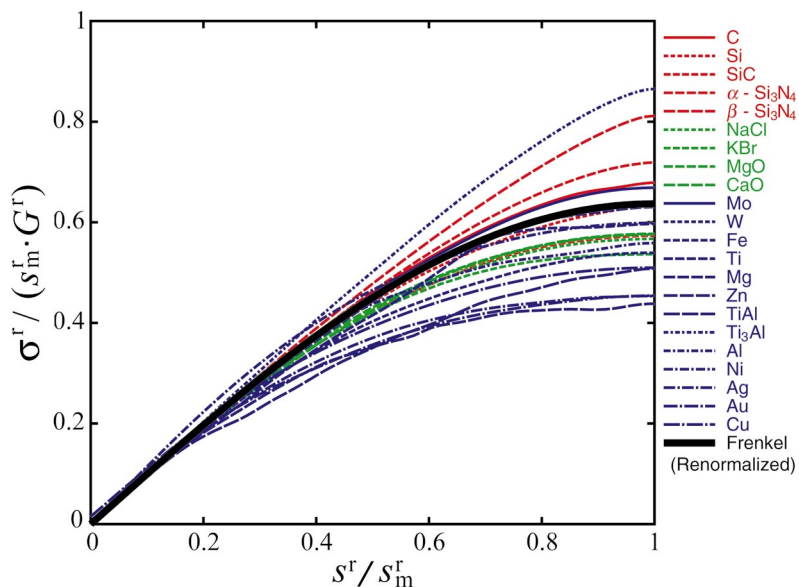


FIG. 3. (Color) Relaxed shear stress-strain curves of 22 materials, rescaled such that all have unit slope initially and reach maximum at 1. The renormalized Frenkel model Eq. (1) is shown for comparison.

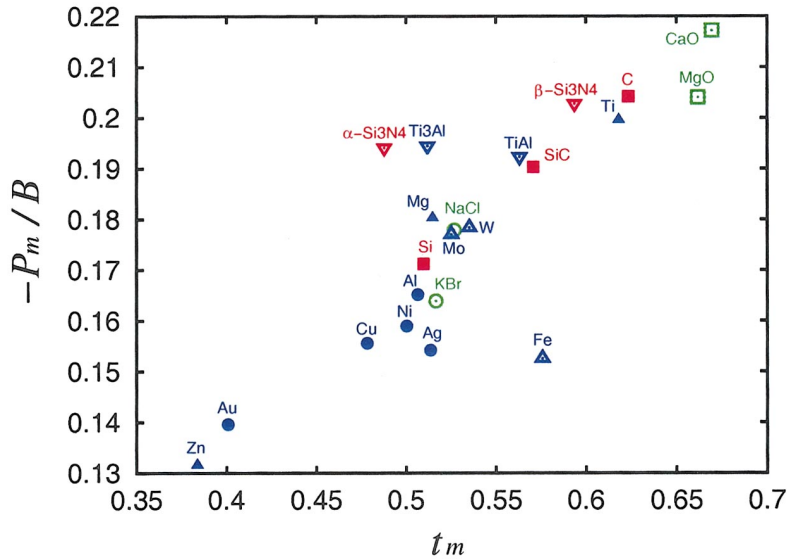


FIG. 4. (Color) Ideal tensile strengths and tensibilities (volumetric) of 22 materials. Note the narrower range of data compared to Fig. 1.

alloy design, for instance to predict the best compromise between ductility and corrosion resistance in stainless steels.³⁵ But s_m and t_m , while easy to obtain in *ab initio* calculations,¹⁰ are unavailable experimentally and therefore have never been used in a practical manner, despite having been theoretically established to be important.^{6,7} Our results, along with other DFT calculations,^{8–12,17–19} indicate that a wide gap in β exists between metals and ceramics because

G/B and s_m are governed not only by the crystal structure, but also by the nature of bonding (e.g., $s_m^r=0.105$ in FCC Au vs $s_m^r=0.200$ in FCC Al) and the loading condition (e.g., $s_m^r=0.221$ vs $s_m^u=0.658$ in B1 NaCl). On the other hand, the relative variation of t_m is less sensitive than s_m , and it has no spectral gap (see Table III and Fig. 4). Besides controlling dislocation nucleation^{5,7} via Eq. (2), s_m also control dislocation mobility. Based on the model of Foreman *et al.*,⁶ it can

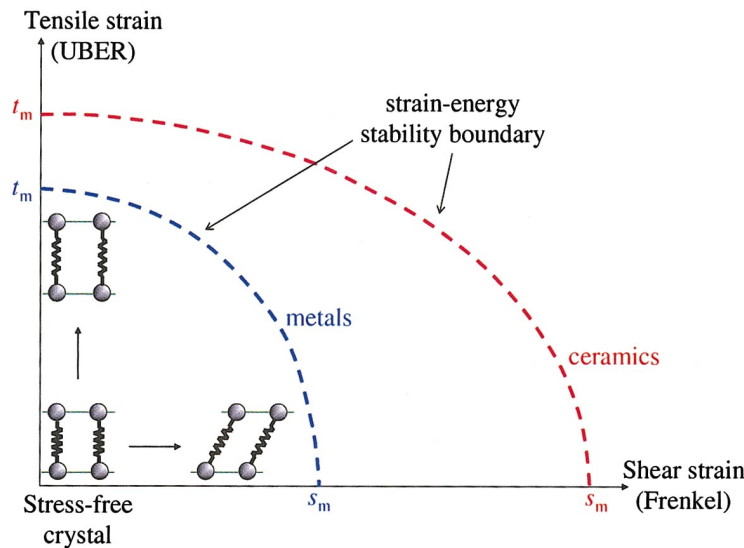


FIG. 5. (Color) Schematic map of material ideal strengths, showing stability boundaries (dashed curves) of the affine strain energy landscapes for metals and ceramics, beyond which bonds break spontaneously in a perfect crystal (Ref. 34). s_m and t_m indicate the maximum stable engineering shear and volumetric tensile strains of a perfect crystal, respectively. Ceramics tend to have larger shearability s_m than metals, with s_m depending not only on the crystal structure (reference value is $b/4d_0$), but also on the nature of bonding (e.g., 0.105 in FCC Au vs 0.200 in FCC Al), and the loading condition (e.g., 0.221 in relaxed vs 0.658 in unrelaxed shear, in NaCl). In contrast, the relative variation of tensibility t_m of solids is more limited (0.38–0.67 in the 22 materials studied). As in the Universal Binding Energy Relation (UBER) (Ref. 2) for tension, a two-parameter model for shear can be established by modifying the empirical formula of Frenkel (Ref. 1). Based on Figs. 1, 3, and 4 and elastic moduli for shear and tension, a simple scaling relation Eq. (2) suggests it is much more difficult to break bonds in ceramic solids in shear than in metals, relative to in tension. Electronic-structure features such as valence charge localization and anisotropy are found to correlate strongly with mechanical-response features during deformation [see Fig. 2 and Supplementary Material (Ref. 22)], such as the shearability.

be shown that increasing the “skewness” $s_m/(b/4d_0)$ of $\sigma(s)$ while keeping G fixed leads to sharply increased Peierls stresses.^{3,4}

Our finding is summarized in Fig. 5. We believe there is sufficient basis, in terms of theoretical formulation^{1,5-7} and *ab initio* property data,^{8-12,17-19} to propose that the shearability s_m of a perfect crystal is an important character of the material. Like the elastic constants, it is a material-specific property that can be determined by first-principles calculations and used in materials design and selection at the mac-

roscopic level. Unlike the elastic constants which pertain to the solid at equilibrium, it reflects quantitatively the electronic and atomic response of the solid at the point of bond breaking.

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